

TENTATIVE

TOSHIBA FAST RECOVERY DIODE SILICON DIFFUSED TYPE

1200JXH23

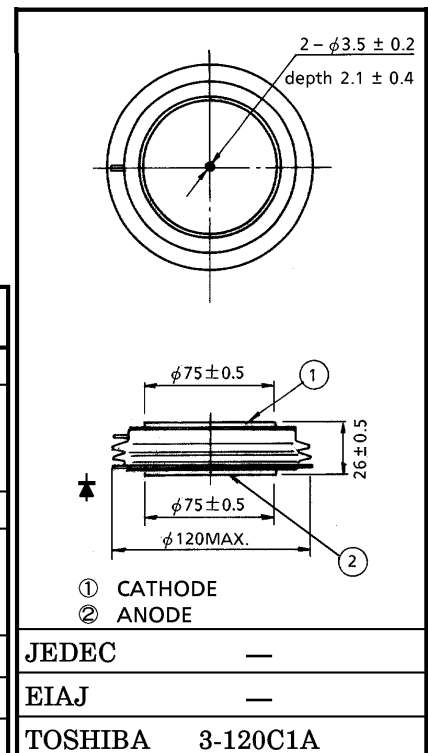
HIGH SPEED RECTIFIER APPLICATIONS

Unit in mm

- Repetitive Peak Reverse Voltage : $V_{RRM} = 6000\text{ V}$
- Average Forward Current : $I_F(AV) = 1200\text{ A}$
- Double Side Cooling

MAXIMUM RATING

CHARACTERISTIC	SYMBOL	RATING	UNIT
Repetitive Peak Reverse Voltage	V_{RRM}	6000	V
Non-Repetitive Peak Reverse Voltage (Non-Repetitive $\leq 5\text{ ms}$, $T_j \leq 0\sim 125^\circ\text{C}$)	V_{RSM}	6300	V
Average Forward Current	$I_F(AV)$	1200	A
Peak One Cycle Surge Forward Current (Non-Repetitive, 10 ms Width Half Sine Waveform)	I_{FSM}	15000	A
Junction Temperature Range	T_j	$-40\sim 125$	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	$-40\sim 125$	$^\circ\text{C}$
Mounting Force	—	37.3 ± 7.8	kN



Weight : 1300 g

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION	TYP.	MAX	UNIT
Repetitive Peak Reverse Current	I_{RRM}	$V_{RRM} = 4500\text{ V}$, $T_j = 125^\circ\text{C}$	—	150	mA
Peak Forward Voltage	V_{FM}	$I_{FM} = 3800\text{ A}$, $T_j = 125^\circ\text{C}$	—	4.4	V
Reverse Recovery Charge	Q_{rr}	$I_F = 1200\text{ A}$, $T_j = 125^\circ\text{C}$ $di_F/dt = 100\text{ A}/\mu\text{s}$	—	4000	μC
Thermal Resistance	$R_{th(j-f)}$	Junction to Fin	—	0.012	$^\circ\text{C}/\text{W}$

961001EAA1

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

